As a below named inventor, I hereby declare that:

I believe I am an original and first inventor of the subject matter which is claimed and for which a patent is sought on the invention entitled <u>SEMICONDUCTOR DEVICE AND METHOD OF PROVIDING REGIONS OF LOW SUBSTRATE CAPACITANCE</u> under Attorney Docket No. <u>ONS00317</u> in the Nonprovisional Utility Patent Application attached hereto.

The following persons are named as the inventors in the Nonprovisional Utility Patent Application:

Guy E. Averett, Keith G. Kamekona, Chandrasekhara Sudhama, Weizhong Cai, Gordon L. Bratten, Bladimiro Ruiz, Jr..

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I hereby appoint the following attorney(s) and/or agent(s) of record to prosecute this Patent Application and to transact all business in the U.S. Patent and Trademark Office connected therewith:

James J. Stipanuk, Reg. No. 44,358, having correspondence address of ON Semiconductor, Patent Administration Dept - MD A700, P.O. Box 62890, Phoenix, AZ 85082-2890, telephone no. (602) 244-5603, fax no. (602) 244-3169.

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the Patent Application or any patent issued thereon.

Signature for Guy E. Averett

Date

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Signature for Chandrasekhara Sudhama

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Signature for Weizhong Qa

Date

2/7/2002

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Signature for Gordon L. Bratten

1 Feb., 2002

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Signature for Bladimiro Ruz,

 $\frac{2/7/02}{Date}$